

1. General description

Ultrafast power diode in a SOD59 (2-lead TO-220AC) plastic package.

2. Features and benefits

- Fast switching
- Low leakage current
- Low forward voltage drop
- Low thermal resistance
- Soft recovery characteristic

3. Applications

- High frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _R	reverse voltage	DC	-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 109 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	-	10	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	-	80	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	-	88	A
Static chara	acteristics		· ·	·		
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.5	2	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 6</u>	-	-	1.6	V
Dynamic ch	naracteristics	·		·		
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 50 A/μs; T _j = 25 °C; <u>Fig. 7</u>	-	35	50	ns

5. Pinning information

Table 2. F	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	К — К — А
2	А	anode	$2 \cap 4$	001aaa020
mb	mb	mounting base; connected to cathode	C C C C C C C C C C C C C C C C C C C	

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BYV10-600P	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59			

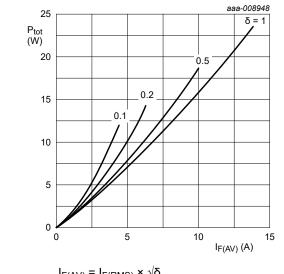
BYV10-600P

7. Limiting values

Table 4. Limiting values

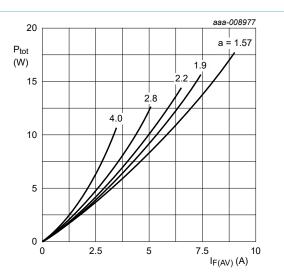
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	δ = 0.5; T _{mb} ≤ 109 °C; square-wave pulse; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	10	A
I _{FRM}	repetitive peak forward current	$\begin{array}{l} \delta = 0.5 \hspace{0.2cm} ; \hspace{0.1cm} t_p = 25 \hspace{0.1cm} \mu s; \hspace{0.1cm} T_{mb} \leq \hspace{0.1cm} 109 \hspace{0.1cm} ^{\circ}C; \\ square-wave \hspace{0.1cm} pulse \end{array}$	-	20	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	80	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	88	A
T _{stg}	storage temperature		-65	175	°C
Tj	junction temperature		-	175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 1.268 \; V; \; R_s = 0.031 \; \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



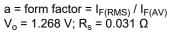
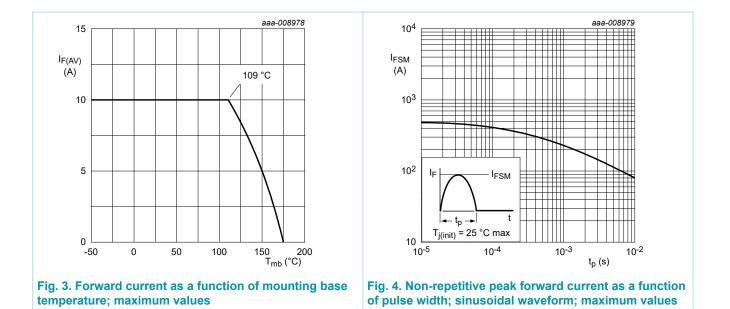


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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BYV10-600P

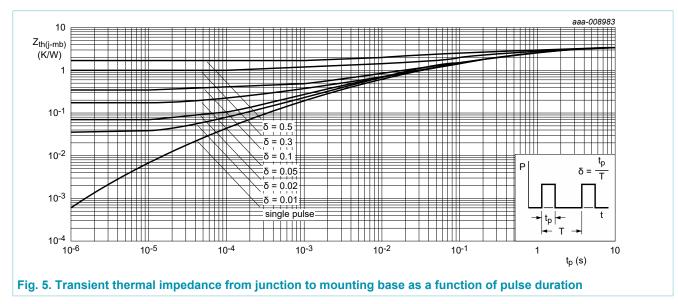
Ultrafast power diode



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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	3.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

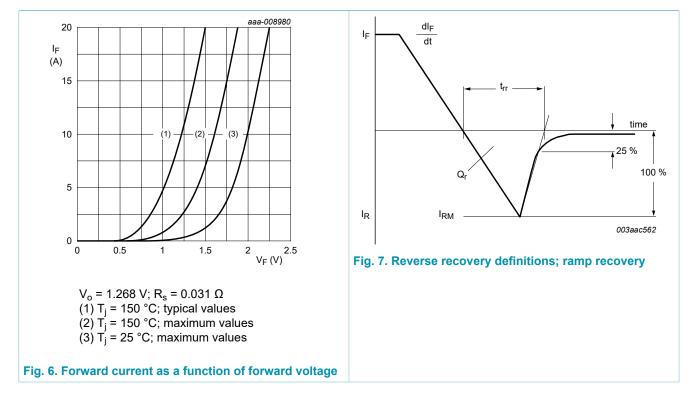


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9. Characteristics

Table 6. Cha	racteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static chara	acteristics						
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u>	-		1.5	2	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 6</u>	-	•	-	1.6	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-		-	10	μA
		V _R = 500 V; T _j = 150 °C	-	•	-	250	μA
Dynamic ch	naracteristics						
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 50 A/μs; T _j = 25 °C; <u>Fig. 7</u>	-	•	35	50	ns
		I_F = 1 A; V _R = 30 V; dI _F /dt = 100 A/µs; T _j = 25 °C; <u>Fig. 7</u>	-		20	-	ns
		I_F = 10 A; V_R = 200 V; dI_F/dt = 200 A/ µs; T_j = 25 °C; <u>Fig. 7</u>	-	•	40	-	ns





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10. Package outline

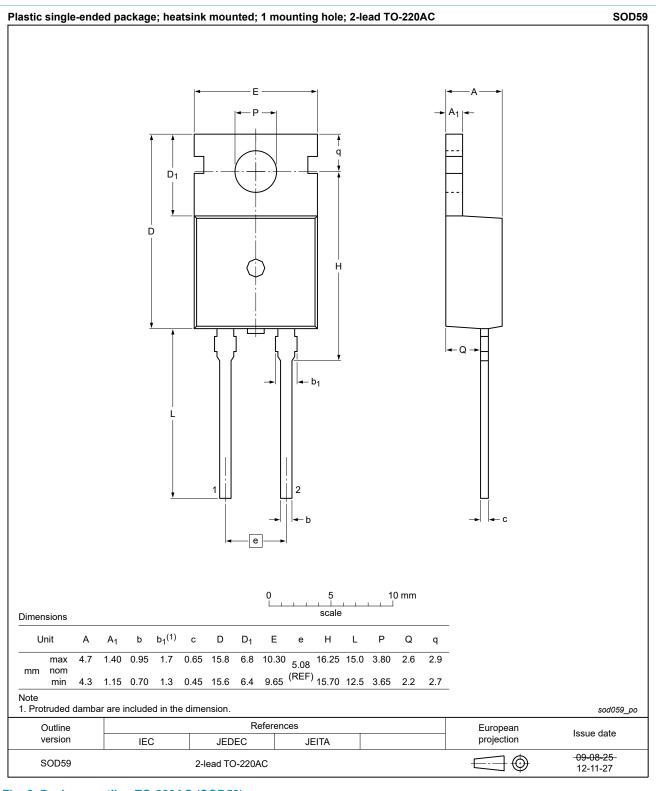


Fig. 8. Package outline TO-220AC (SOD59)

BYV10-600P

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11. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
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- [2] The term 'short data sheet' is explained in section "Definitions".
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